

General Description

The WSF15N10G uses advanced SGTMOS technology to provide low RDS(ON), low gate charge, fast switching and excellent avalanche characteristics. This device is specially designed to get better ruggedness and suitable to use in Synchronous rectification applications

Product Summery

BVDSS	RDSON	ID
100V	75mΩ	15A

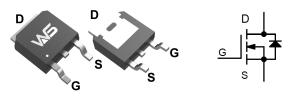
Applications

- Fast Switching
- DC-DC Power System
- Load Switch

Features

- advanced SGTMOS technology
- Low gate charge
- Low R_{DS(ON)}

TO-252 Pin Configuration



Absolute Maximum Ratings at Tj=25 °C unless otherwise noted

Symbol	Parameter	Rating	Units	
V _{DS}	Drain-Source Voltage	100	V	
V _{GS}	Gate-Source Voltage	±20	V	
I _D	Continuous Drain Current ¹⁾	15	A	
I _{D, pulse}	Pulsed Drain Current ²⁾	45	А	
E _{AS}	Single Pulse Avalanche Energy ⁴⁾	5.5	mJ	
PD	Total Power Dissipation ³⁾	36	W	
T _{STG}	Storage Temperature Range -55 to 1		°C	
TJ	Operating Junction Temperature Range -55 to 150		°C	

Thermal Data

Symbol	Parameter	Тур.	Max.	Unit
R _{θJA}	Thermal Resistance Junction-ambient ⁵⁾		62	°C/W
R _{θJC}	Thermal Resistance Junction-Case		3.5	°C/W



N-Ch MOSFET

Electrical Characteristics (T_J=25¹C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	100			V
$\triangle BV_{DSS} / \triangle T_J$	BVDSS Temperature Coefficient	Reference to 25 $^\circ\!\mathrm{C}$, I_D=1mA		0.098		V/℃
Б	Static Drain-Source On-Resistance ²	V _{GS} =10V , I _D =5A		50	75	mΩ
R _{DS(ON)}		V _{GS} =4.5V , I _D =2A		60	90	mΩ
V _{GS(th)}	Gate Threshold Voltage	V_{GS} = V_{DS} , I_D =250 uA	1.2		2.5	V
	Drain-Source Leakage Current	V_{DS} =80V , V_{GS} =0V , T_{J} =25 $^{\circ}$ C			1	uA
I _{DSS}		V_{DS} =80V , V_{GS} =0V , T_{J} =55 $^{\circ}$ C			5	
I _{GSS}	Gate-Source Leakage Current	$V_{GS}=\pm20V$, $V_{DS}=0V$			±100	nA
Rg	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz		28.8		Ω
Qg	Total Gate Charge (10V)	V _{GS} =10 V ,		6.5		
Q _{gs}	Gate-Source Charge	V _{DS} =50 V,		1.4		nC
Q _{gd}	Gate-Drain Charge	I _D =5 A		1.4		
T _{d(on)}	Turn-On Delay Time	V _{GS} =10 V,		14		
Tr	Rise Time	V _{DS} =50 V,		3.2		
T _{d(off)}	Turn-Off Delay Time	R _G =2 Ω,		36		ns
T _f	Fall Time	I _D =5 A		14		
Ciss	Input Capacitance	V _{GS} =0 V,		310		
C _{oss}	Output Capacitance	V _{DS} =25 V,		80		pF
C _{rss}	Reverse Transfer Capacitance	<i>f</i> =100 KHz		50		

Diode Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Is	Continuous diode current ¹⁾	$V_G = V_D = 0V$, Force Current			15	А
I _{SP}	Pulsed diode current ²⁾				45	А
V _{SD}	Diode Forward Voltage ²⁾	V _{GS} =0V , I _S =5A , T _J =25℃			1.3	V
t _{rr}	Reverse Recovery Time	IF=5A ,		36		nS
Qrr	Reverse Recovery Charge	dl/dt=100A/µs , Tյ=25℃		37		nC

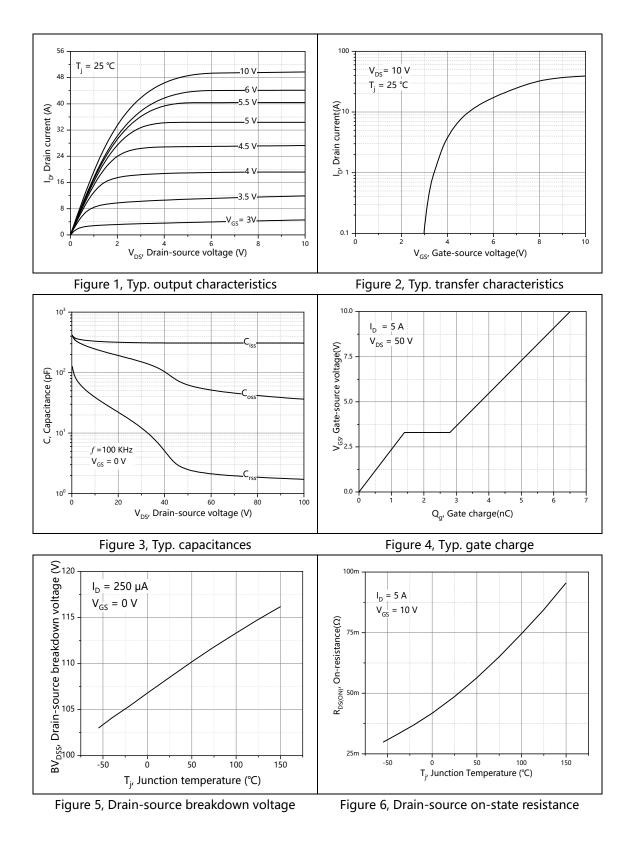
- 1) Calculated continuous current based on maximum allowable junction temperature.
- 2) Repetitive rating; pulse width limited by max. junction temperature.
- 3) Pd is based on max. junction temperature, using junction-case thermal resistance.
- 4) V_{DD} =50 V, R_G=25 Ω , L=0.3 mH, starting T_j=25 °C.
- 5) The value of $R_{\theta JA}$ is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with $T_a=25$ °C.



WSF15N10G

N-Ch MOSFET

Typical Characteristics







N-Ch MOSFET

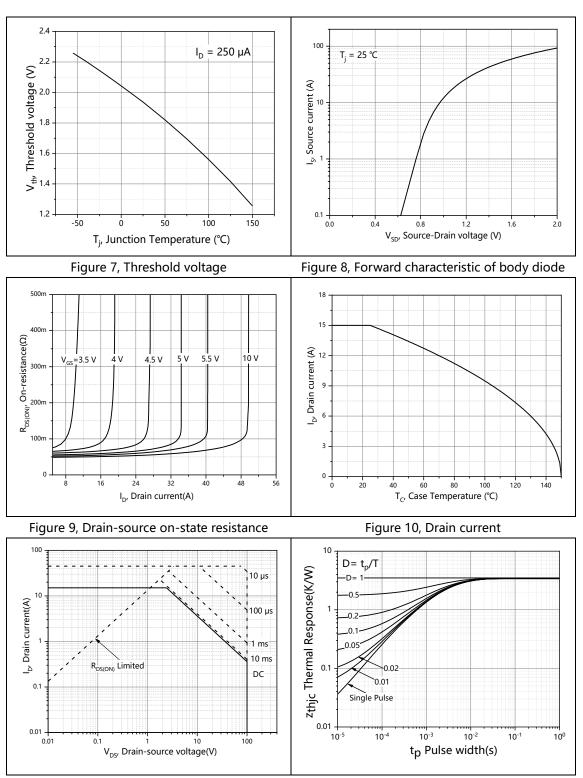


Figure 11, Safe operation area $T_C=25$ °C

Figure 12, Max. transient thermal impedance



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